International

SCHOTTKY RECTIFIER

MBR16..PbF Series

16 Amp

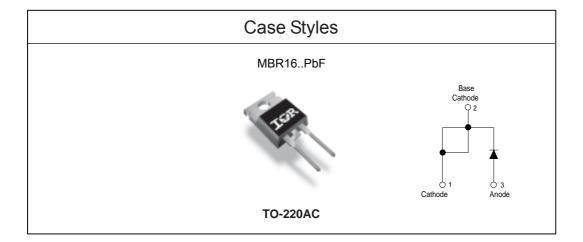
Major Ratings and Characteristics

Characteristics	Values	Units
I _{F(AV)} Rectangular waveform	16	A
V _{RRM}	35-45	V
I_{FSM} @ tp = 5 µs sine	1800	А
V _F @16 Apk, T _J = 125°C	0.57	V
TJ	- 65 to 150	°C

Description/Features

The MBR16..PbF Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150°C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- 150°C T_J operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead-Free ("PbF" suffix)



MBR16..PbF Series

International **tor** Rectifier

Voltage Ratings

Part number	MBR1635PbF	MBR1645PbF
V _R Max. DC Reverse Voltage (V)		
V _{RWM} Max. Working Peak Reverse Voltage (V)	35	45

Absolute Maximum Ratings

	Parameters	MBR16	Units	Conditions
I _{F(AV)}	Max. Average Forward Current	16	А	@ $T_c = 134 \degree C (Rated V_R)$
I _{FSM}	Non-Repetitive Peak Surge Current	1800	٨	5µs Sine or 3µs Rect. pulse Following any rated load condition and with rated V_{RRM} applied
		150	A	Surge applied at rated load condition halfwave single phase 60Hz
E _{AS}	Non-Repetitive Avalanche Energy	24	mJ	$T_J = 25 \degree C, I_{AS} = 3.6 \text{ Amps}, L = 3.7 \text{ mH}$
I _{AR}	Repetitive Avalanche Current	3.6	A	Current decaying linearly to zero in 1 μ sec Frequency limited by T _J max. V _A = 1.5 x V _R typical

Electrical Specifications

	Parameters	MBR16	Units	(Conditions
V _{FM}	Max. Forward Voltage Drop (1)	0.63	V	@ 16A	T _J = 25 °C
		0.57	V	@ 16A	T _J = 125 °C
I _{RM}	Max. Instantaneus Reverse Current	0.2	mA	T _J = 25 °C	Dated DC valtage
	(1)	40	mA	T _J = 125 °C	Rated DC voltage
CT	Max. Junction Capacitance	1400	рF	$V_{R} = 5V_{DC}$ (test signal range 100Khz to 1Mhz) 25°C	
Ls	Typical Series Inductance	8.0	nH	Measured from top of terminal to mounting plane	
dv/dt	Max. Voltage Rate of Change	10000	V/ µs		
	(Rated V _R)				

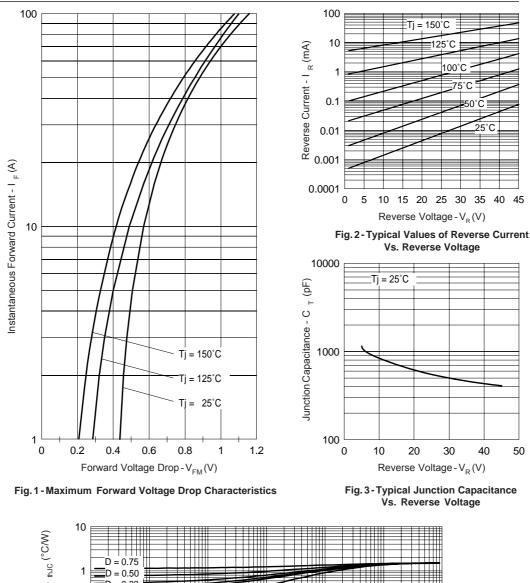
(1) Pulse Width < 300µs, Duty Cycle <2%

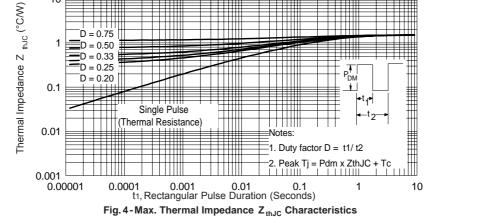
Thermal-Mechanical Specifications

	Parameters		MBR16	Units	Conditions
TJ	Max. Junction Temperature R	lange	-65 to 150	°C	
T _{stg}	Max. Storage Temperature R	ange	-65 to 175	°C	
R _{thJC}	Max. Thermal Resistance Jur to Case	nction	1.50	°C/W	DC operation
R _{thCS}	Typical Thermal Resistance, to Heatsink	Case	0.50	°C/W	Mounting surface, smooth and greased
wt	Approximate Weight		2 (0.07)	g(oz.)	
Т	Mounting Torque	Min.	6(5)	Kg-cm	
		Max.	12(10)	(lbf-in)	
	Case Style		TO-220AC		JEDEC
	Marking Device		MBR1645		

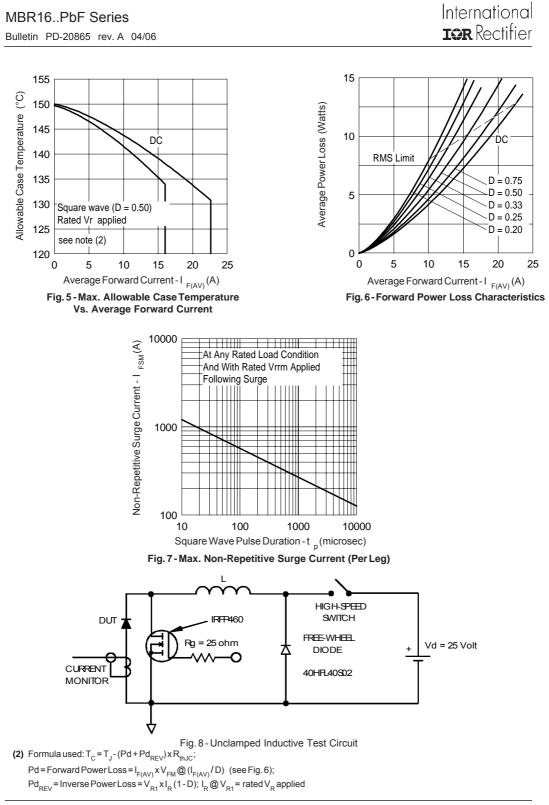
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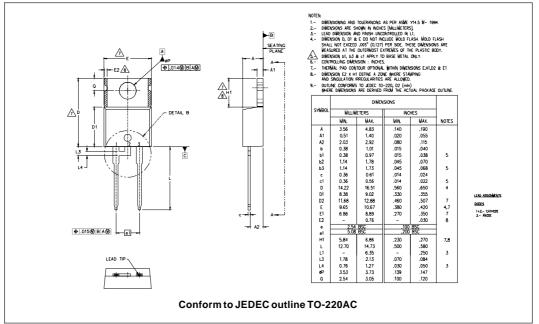


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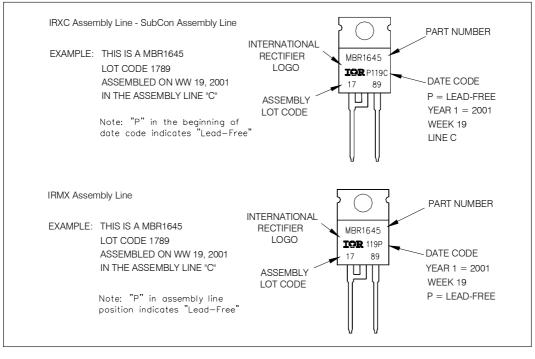
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Outline Table

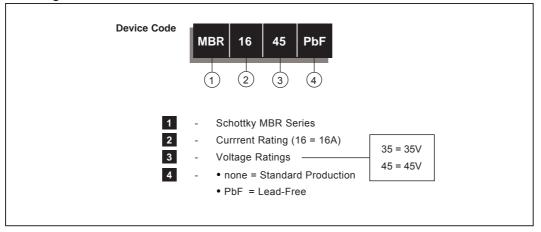


Part Marking Information



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Ordering Information Table



Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level and Lead-Free. Qualification Standards can be found on IR's Web site.



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